



A Product Line of Diodes Incorporated

DMP4025LSS

40V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)} max	I _D max (A) T _A = 25°C (Notes 6)
-40V	$25m\Omega @ V_{GS} = -10V$	-8.0
-400	$45m\Omega @ V_{GS} = -4.5V$	-6.0

Description and Applications

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor control
- Backlighting
- DC-DC Converters
- Printer equipment

Features and Benefits

- Low R_{DS(on)} Minimizes conduction losses
- Fast switching speed Minimizes switching losses
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

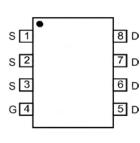
Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.074 grams (approximate)

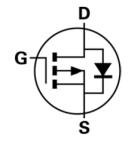


SO-8

Top View



Pin-Out Top View



Device symbol

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMP4025LSS-13	P4025LS	13	12	2,500

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
 Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com

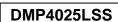
Marking Information

Notes:



>II = Manufacturer's Marking
P4025LS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 10 = 2010)
WW = Week (01 - 53)





Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Units	
Drain-Source Voltage			V _{DSS}	-40	N/
Gate-Source Voltage		V _{GSS}	±20	v	
Continuous Drain Current V _{GS} = -10V	(Notes 6)		-8.0		
	$V_{GS} = -10V$	-10V T _A = 70°C (Notes 6)	ID	-6.9	
	(Notes 5)		-6.0		
Pulsed Drain Current	$V_{GS} = -10V$	(Notes 7)	I _{DM}	-30	A
Continuous Source Current (Body diode)		(Notes 7)	Is	-8.0	
Pulsed Source Current (Body diode) (Notes 7)		(Notes 7)	I _{SM}	-30	

Thermal Characteristics @T_A = 25°C unless otherwise specified

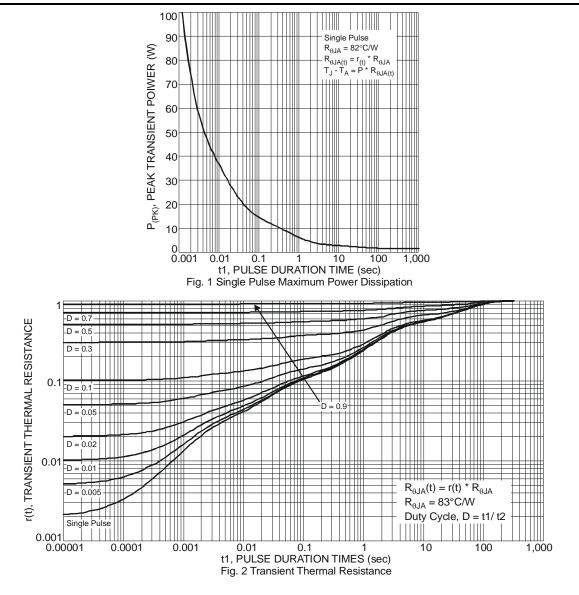
Characteristic		Symbol	Value	Unit
Dower Discinction	(Notes 5)	В	1.52	W
Power Dissipation	(Notes 6)	P _D	2.4	VV
Thermal Resistance, Junction to Ambient	(Notes 5)		82	
	(Notes 6)	R _{0JA}	52	°C/W
Thermal Resistance, Junction to Lead	(Notes 8)	R _{θJL}	48.85	
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

 For a device surface mounted on minimum recommended FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
 Same as note (2), except the device is surface mounted on 25mm X 25mm X 1.6mm FR4 PCB.
 Repetitive rating on 25mm X 25mm FR4 PCB, D=0.02, pulse width 300µs – pulse width by maximum junction temperature.
 Thermal resistance from junction to solder-point (at the end of the drain lead). Notes:



DMP4025LSS

Thermal Characteristics







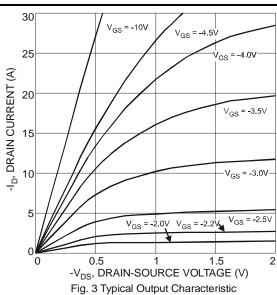
Electrical Characteristics T_A = 25°C unless otherwise specified

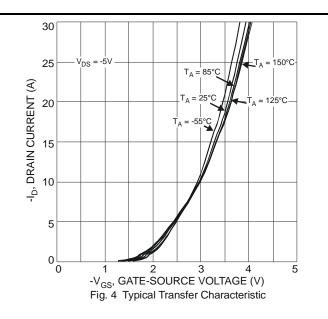
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS						•	
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$I_D = -250 \mu A, V_{GS} = 0 V$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1.0	μΑ	$V_{DS} = -40V, V_{GS}$	s = 0V
Gate-Source Leakage	IGSS	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	-0.8	-1.3	-1.8	V	$I_D = -250 \mu A, V_D$	s = V _{GS}
Statia Drain Source On Registence (Note 0)	Р		18	25	mΩ	V _{GS} = -10V, I _D = -3A	
Static Drain-Source On-Resistance (Note 9)	R _{DS (ON)}	_	30	45	11152	$V_{GS} = -4.5V, I_{D}$	= -3A
Forward Transconductance (Notes 9 & 10)	g fs	_	16.6	_	S	$V_{DS} = -5V, I_D = -3A$	
Diode Forward Voltage (Note 9)	V _{SD}	_	-0.7	-1.0	V	$I_{S} = -1A, V_{GS} = 0V$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{iss}	_	1640	_		$V_{DS} = -20V, V_{GS} = 0V$ f = 1MHz	
Output Capacitance	Coss	_	179	_	pF		
Reverse Transfer Capacitance	C _{rss}	_	128	_			
Gate Resistance	R _g	_	6.43	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (Note 11)	Qg	_	14.0	_		$\begin{tabular}{ c c c c c } \hline $V_{GS} = -4.5V$ \\ \hline $V_{DS} = -20V$ \\ \hline $V_{DS} = -20V$ \\ \hline $I_D = -3A$ \\ \hline \end{tabular}$	
Total Gate Charge (Note 11)	Qg	_	33.7	_			$V_{DS} = -20V$
Gate-Source Charge (Note 11)	Q _{gs}	_	5.5	_	nC		I _D = -3A
Gate-Drain Charge (Note 11)	Q _{gd}	_	7.3	_			
Turn-On Delay Time (Note 11)	t _{D(on)}	_	6.9	_		V _{DD} = -20V, V _{GS} = -10V I _D = -3A	
Turn-On Rise Time (Note 11)	tr		14.7	_	n 0		
Turn-Off Delay Time (Note 11)	t _{D(off)}		53.7	_	ns		
Turn-Off Fall Time (Note 11)	tf		30.9	_			

9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s;$ duty cycle $\leq 2\%$ Notes:

For design aid only, not subject to production testing.
 Switching characteristics are independent of operating junction temperatures.

Typical Characteristics

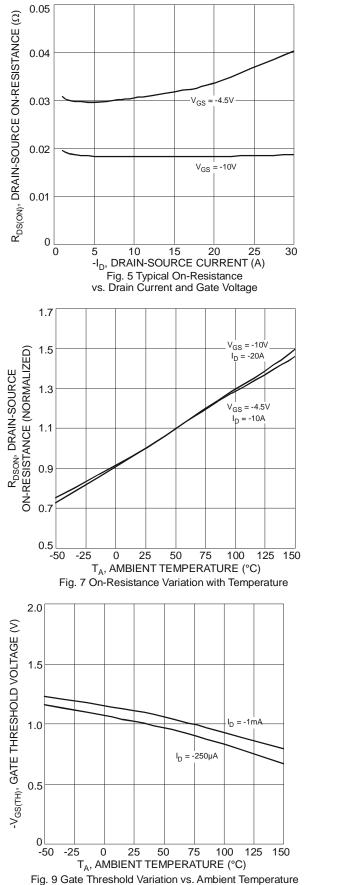


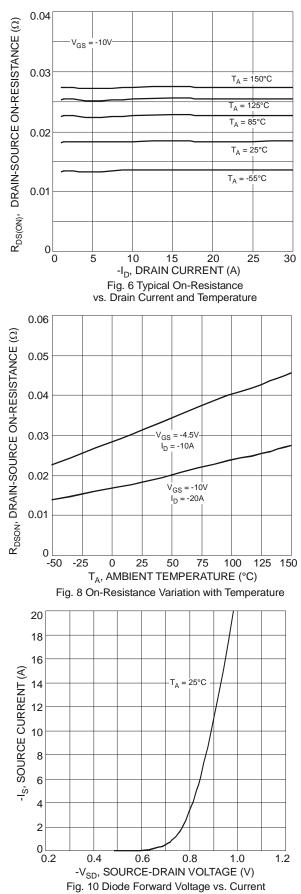










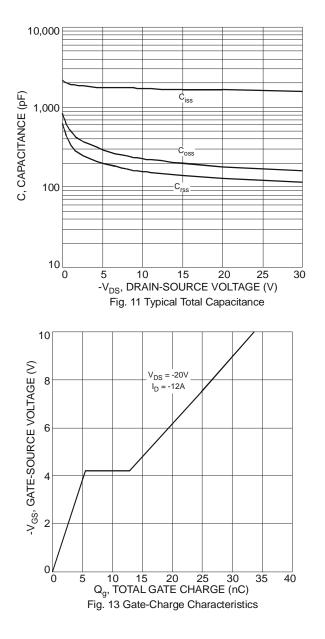


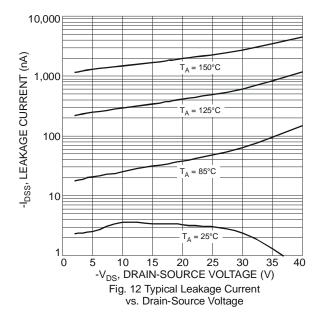


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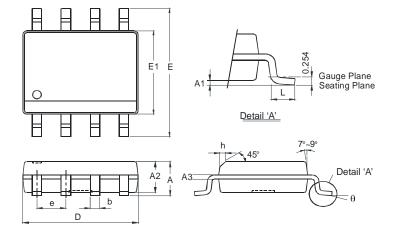






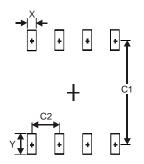
DMP4025LSS

Package Outline Dimensions



SO-8						
Dim	Min Max					
Α	-	1.75				
A1	0.10	0.20				
A2	1.30	1.50				
A3	0.15	0.25				
b	0.3	0.5				
D	4.85	4.95				
Е	5.90	6.10				
E1	3.85 3.95					
е	е 1.27 Тур					
h	- 0.35					
Г	0.62	0.82				
θ	0° 8°					
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27



DMP4025LSS

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